NSN 5961-00-987-4623

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-987-4623 **Inclosure Material:** Glass and metal **Overall Length:** 1.000 inches **Overall Diameter:** 1.000 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 1600.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No